NSN 5961-00-099-9809

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-099-9809 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage, dc and 50.0 collector to emitter voltage, dc all transistor **Current Rating Per Characteristic:** 600.00 milliamperes collector current, dc all transistor **Power Rating Per Characteristic:** 600.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Design analysis; transistors junction pattern arrangements are npn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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